SUPERTEX INC OF

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VC0206N6 VC0206N7

### Complementary Enhancement-Mode Vertical DMOS Power FETs Quad Array

### Ordering Information

BV <sub>pss</sub> /	R <sub>DS(ON)</sub> (max) Q1 + Q2 or Q3 + Q4	Order Number / Package	
BV <sub>DGS</sub>		14-Pin P-Dip	14-Pin C-Dip*
60V	6Ω	VC0206N6	VC0206N7

<sup>\*14-</sup>pin Side Brazed Ceramic Dip.

#### **Features**

- ☐ 4 independent channels
- ☐ 4 electrically isolated die
- ☐ Commercial and Military versions available
- ☐ Freedom from secondary breakdown
- □ Low power drive requirement
- □ Low C<sub>iss</sub> and fast switching speeds
- ☐ High input impedance and high gain
- ☐ Complementary N- and P-Channel devices

## **Applications**

- □ Motor control
- □ Convertors
- □ Amplifiers
- ☐ Switches
- Power supply circuits
- Driver (Relays, Hammers, Solenoids, Lamps, Memories, Displays, Bipolar Transistors, etc.)

### Thermal Characteristics

Package		Plastic DIP	Ceramic DIP
I <sub>D</sub> continuous & I <sub>DR</sub> (single die)	N-Channel	0.86A	1.0A
	P-Channel	0.6A	0.7A
I <sub>D</sub> pulsed*	N-Channel	4.0A	4.0A
& I <sub>DRM</sub> +	P-Channel	2.5A	2.5A
Power Dissipation @ T <sub>C</sub> = 25°C‡		3W	4W
θ <sub>ja</sub> (°C/W)		83.3	62,5
θ <sub>jc</sub> (°C/W)		41.6	31.2

Pulse test 300 μS pulse, 2% duty cycle WW.DZSC.COM

## Advanced DMOS Technology

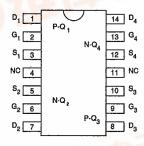
These enhancement-mode (normally-off) power transistors utilize a vertical DMOS structure and Supertex's well-proven silicongate manufacturing process. This combination produces devices with the power handling capabilities of bipolar transistors and with the high input impedance and negative temperature coefficient inherent in MOS devices. Characteristic of all MOS structures, these devices are free from thermal runaway and thermallyinduced secondary breakdown.

Supertex Vertical DMOS Power FETs are ideally suited to a wide range of switching and amplifying applications where high breakdown voltage, high input impedance, low input capacitance, and fast switching speeds are desired.

### **Electrical Characteristics**

Refer to VN02A and VP02A Data Sheets for detailed characteristics of N- and P-Channel devices.

# Pin Configuration



top view 14-pin DIP